

## CIR-S4SUSY2916G

DDR4 SO-DIMM 2933MHz 16GB

Density Pin Count Type Dimensions	16GB 260pin Unbuffered		
Туре	Unbuffered		
Differisions	69.60mm x 30.00mm Non-ECC 1G x 8 bit 2933 MHz 21 1.2V 10 0°C~+85°C Dual Rank		
FCC			
Component Config			
Data Rate			
CAS Latency			
Voltage			
PCB Layers			
Operating Temp.(TCASE)			
Module Ranks			
	CAS Latency Voltage PCB Layers Operating Temp.(TCASE)		

## Features

- JEDEC Standard 260-pin Small Outline Dual In-Line Memory Module
- Intend for PC4-2933 applications
- Inputs and Outputs are SSTL-12 compatible
- VDD=VDDQ = 1.2V±0.06V (1.14V~1.26V)
- Programmable CAS Latency(posted CAS): 11,12,13,14,15,16,17,18,19,20,21
- Low-Power auto self-refresh (LPASR)
- SDRAMs have 16 internal banks for concurrent operation (4 Bank Group of 4 banks each)
- Normal and Dynamic On-Die Termination for data, strobe and mask signals
- Data bus inversion (DBI) for data bus
- Fixed burst chop (BC) of 4 and burst length (BL) of 8 via the MRS
- Selectable BC4 or BL8 on-the fly (OTF)
- Fly-By topology
- Terminated control, command and address bus
- RoHS and Halogen free



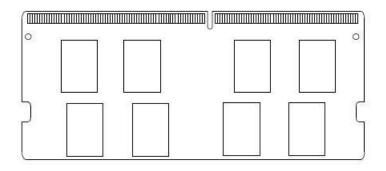
**Speed Grade** 

Frequency Grade	Data	CAS Latency Support											
	ade Rate	CL11	CL12	CL13	CL14	CL15	CL16	CL17	CL18	CL19	CL20	CL21	CL-tRCD-tRP
DDR4-2933	PC4-23466	1600	1600	1866	1866	2133	2133	2400	2400	2666	2666	2933	21-21-21

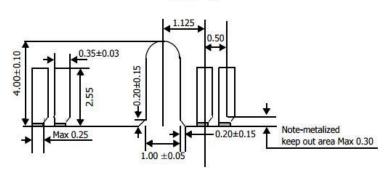
## **Package Dimensions**

Side Front 69.60mm 3.59mm max 1.75 4.00±0.10 00.00 18.00 20.00 Detail-A 0 6.00 pin 260 1.425 pin 1 2.50 1.675 1.20±.10 28.50 35.50 2.X01.80±0.10

Back



Detail - A



Tolerances : + 0.15mm unless otherwise specified

Unit: mm